ICTE5 thru ICTE18C, 1N6373 thru 1N6386

Vishay General Semiconductor

TRANSZORB® Transient Voltage Suppressors



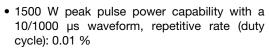
PRIMARY CHARACTERISTICS				
V _{WM}	5.0 V to 18 V			
V _{BR} (uni-directional)	6.0 V to 21.2 V			
V _{BR} (bi-directional)	9.2 V to 21.2 V			
P _{PPM}	1500 W			
P _D	6.5 W			
I _{FSM}	200 A			
T _J max.	175 °C			
Polarity	Uni-directional, bi-directional			
Package	1.5KE			

DEVICES FOR BI-DIRECTION APPLICATIONS

For bi-directional types, use C suffix (e.g. ICTE18C). Electrical characteristics apply in both directions.

FEATURES

- · Glass passivated chip junction
- · Available in uni-directional and bi-directional





- · Excellent clamping capability
- · Very fast response time
- · Low incremental surge resistance
- Solder dip 275 °C max. 10 s, per JESD 22-B106
- AEC-Q101 qualified
- Material categorization: for definitions of compliance please see <u>www.vishay.com/doc?99912</u>

TYPICAL APPLICATIONS

Use in sensitive electronics protection against voltage transients induced by inductive load switching and lighting on ICs, MOSFET, signal lines of sensor units for consumer, computer, industrial, and telecommunication.

MECHANICAL DATA

Case: Molded epoxy body over passivated junction Molding compound meets UL 94 V-0 flammability rating Base P/N-E3 - RoHS-compliant and commercial grade Base P/NHE3_X - RoHS-compliant and AEC-Q101 qualified ("X" denotes revision code e.g. A, B, ...)

Terminals: Matte tin plated leads, solderable per J-STD-002 and JESD 22-B102

E3 suffix meets JESD 201 class 1A whisker test, HE3 suffix meets JESD 201 class 2 whisker test

Polarity: For uni-directional types the color band denotes cathode end, no marking on bi-directional types

MAXIMUM RATINGS (T _A = 25 °C unless otherwise noted)					
PARAMETER	SYMBOL	LIMIT	UNIT		
Peak pulse power dissipation with a 10/1000 μs waveform ⁽¹⁾ (fig. 1)	P _{PPM}	1500	W		
Peak pulse current with a 10/1000 µs waveform (1) (fig. 3)	I _{PPM}	See next table	Α		
Power dissipation on infinite heatsink at T _L = 75 °C (fig. 8)	P_{D}	6.5	W		
Peak forward surge current 8.3 ms single half sine-wave uni-directional only (2)	I _{FSM}	200	Α		
Maximum instantaneous forward voltage at 100 A for uni-directional only	V _F	3.5	V		
Operating junction and storage temperature range	T _J , T _{STG}	-55 to +175	°C		

Notes

- $^{(1)}$ Non-repetitive current pulse, per fig. 3 and derated above T_A = 25 °C per fig. 2
- (2) 8.3 ms single half sine-wave, duty cycle = 4 pulses per minute maximum



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ELECTRICAL CHARACTERISTICS (JEDEC® REGISTERED DATA) (T _A = 25 °C unless otherwise noted)							
JEDEC® TYPE NUMBER	GENERAL SEMICONDUCTOR PART NUMBER	STAND-OFF VOLTAGE V _{WM} (V)	BREAKDOWN VOLTAGE V _{BR} AT 1.0 mA (V) MIN.	MAXIMUM REVERSE LEAKAGE AT V _{WM} I _D (µA)	$\begin{array}{c} \text{MAXIMUM} \\ \text{CLAMPING} \\ \text{VOLTAGE} \\ \text{AT I}_{\text{PP}} = 1.0 \text{ A} \\ \text{V}_{\text{C}} \text{ (V)} \end{array}$	MAXIMUM CLAMPING VOLTAGE AT I _{PP} = 10 A V _C (V)	MAXIMUM PEAK PULSE CURRENT I _{PP} (A)
UNI-DIRECTION	ONAL TYPES						
1N6373 ⁽²⁾	ICTE5 (2)	5.0	6.0	300	7.1	7.5	160
1N6374	ICTE8	8.0	9.4	25.0	11.3	11.5	100
1N6375	ICTE10	10.0	11.7	2.0	13.7	14.1	90
1N6376	ICTE12	12.0	14.1	2.0	16.1	16.5	70
1N6377	ICTE15	15.0	17.6	2.0	20.1	20.6	60
1N6378	ICTE18	18.0	21.2	2.0	24.2	25.2	50
1N6382	ICTE8C	8.0	9.4	50	11.4	11.6	100
BI-DIRECTIONAL TYPES							
1N6383	ICTE10C	10.0	11.7	2.0	14.1	14.5	90
1N6384	ICTE12C	12.0	14.1	2.0	16.7	17.1	70
1N6385	ICTE15C	15.0	17.6	2.0	20.8	21.4	60
1N6386	ICTE18C	18.0	21.2	2.0	24.8	25.5	50

Notes

⁽³⁾ Clamping factor: 1.33 at full rated power; 1.20 at 50 % rated power; clamping factor: the ratio of the actual V_C (clamping voltage) to the V_{BR} (breakdown voltage) as measured on a specific device

ORDERING INFORMATION (Example)						
PREFERRED P/N	UNIT WEIGHT (g)	PREFERRED PACKAGE CODE	BASE QUANTITY	DELIVERY MODE		
ICTE5-E3/54	0.968	54	1400	13" diameter paper tape and reel		
ICTE5HE3_A/C (1)	0.968	С	1400	13" diameter paper tape and reel		

Note

(1) AEC-Q101 qualified

^{(1) &}quot;C" suffix indicates bi-directional

⁽²⁾ ICTE5 and 1N6373 are not available as bi-directional



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RATINGS AND CHARACTERISTICS CURVES (T_A = 25 °C unless otherwise noted)

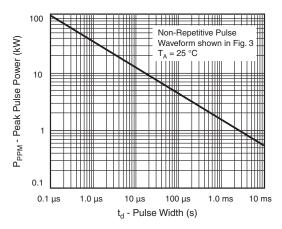


Fig. 1 - Peak Pulse Power Rating Curve

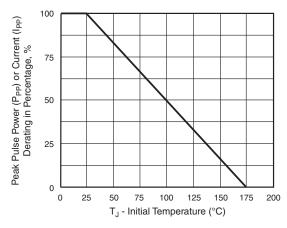


Fig. 2 - Pulse Power or Current vs. Initial Junction Temperature

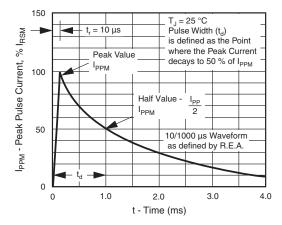


Fig. 3 - Pulse Waveform

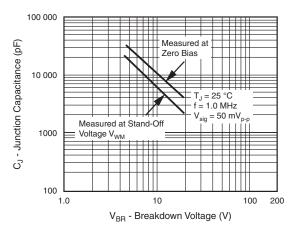


Fig. 4 - Typical Junction Capacitance Uni-Directional

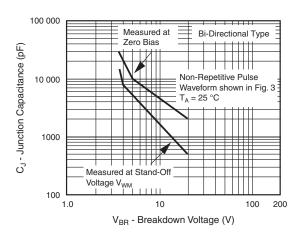


Fig. 5 - Typical Junction Capacitance

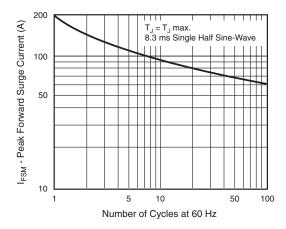


Fig. 6 - Maximum Non-Repetitive Forward Surge Current Uni-Directional Only





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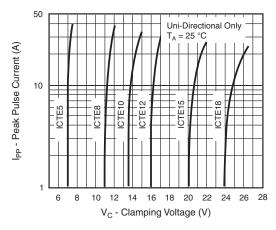


Fig. 7 - Typical Characteristics Clamping Voltage

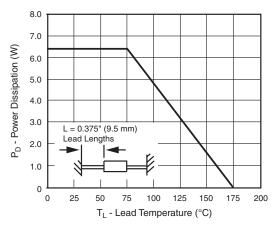
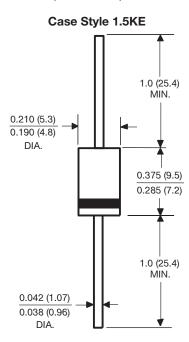


Fig. 8 - Power Derating Curve

PACKAGE OUTLINE DIMENSIONS in inches (millimeters)





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